

# UNISONIC TECHNOLOGIES CO., LTD

## DTC123E

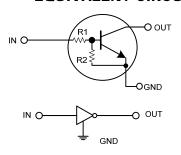
## **NPN SILICON TRANSISTOR**

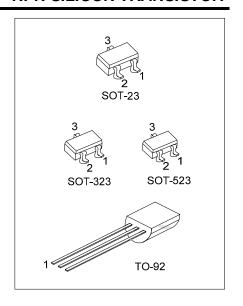
# **DIGITAL TRANSISTORS** (BUILT- IN RESISTORS)

#### **FEATURES**

- \* Built-in bias resistors that implies easy ON/OFF applications.
- \* The bias resistors are thin-film resistors with complete isolation to allow negative input.

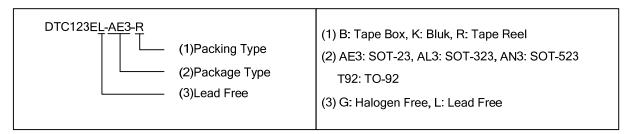
#### **EQUIVALENT CIRCUIT**



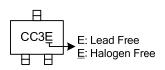


#### **ORDERING INFORMATION**

Ordering Number		Dookogo	Pin Assignment			Dooking	
Lead Free	Halogen Free	Package	1	2	3	Packing	
DTC123EL-AE3-R	DTC123EG-AE3-R	SOT-23	G	I	0	Tape Reel	
DTC123EL-AL3-R	DTC123EG-AL3-R	SOT-323	G	I	0	Tape Reel	
DTC123EL-AN3-R	DTC123EG-AN3-R	SOT-523	G	I	0	Tape Reel	
DTC123EL-T92-B	DTC123EG-T92-B	TO-92	G	0	I	Tape Box	
DTC123EL-T92-K	DTC123EG-T92-K	TO-92	G	0	ı	Bluk	



#### **MARKING**



1 of 3 QW-R206-085,D

#### ■ ABSOLUTE MAXIMUM RATINGS (T<sub>A</sub>=25°C)

PARAMETER		SYMBOL	RATINGS	UNIT
Supply Voltage		V <sub>CC</sub>	50	V
Input Voltage		V <sub>IN</sub>	-10 ~ +12	V
Output Current		I <sub>OUT</sub>	100	mA
Power Dissipation	SOT-523		150	mW
	SOT-23/SOT-323	P <sub>D</sub>	200	mW
	TO-92		625	mW
Junction Temperature		TJ	+150	°C
Storage Temperature		T <sub>STG</sub>	-55 ~ +150	°C

Note Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

## ■ ELECTRICAL SPECIFICATIONS (T<sub>A</sub>=25°C)

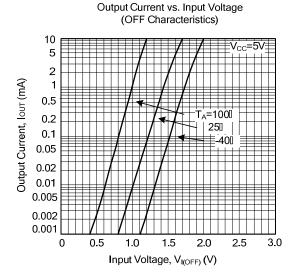
PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Input Voltage	$V_{IN(OFF)}$	V <sub>CC</sub> =5V, I <sub>OUT</sub> =100μA V <sub>OUT</sub> =0.3V, I <sub>OUT</sub> =20mA			0.5	V
	$V_{IN(ON)}$					
Output Voltage	$V_{OUT(ON)}$	$I_{OUT}/I_{IN} = 10$ mA $/0.5$ mA		0.1	0.3	V
Input Current	I <sub>IN</sub>	V <sub>IN</sub> =5V			3.8	mA
Output Current	I <sub>OUT(OFF)</sub>	V <sub>CC</sub> =50V, V <sub>IN</sub> =0V			0.5	μΑ
DC Current Gain	$G_IN$	V <sub>OUT</sub> =5V, I <sub>OUT</sub> =20mA	20			
Input Resistance	R <sub>1</sub>		1.54	2.2	2.86	ΚΩ
Resistance Ratio	R <sub>2</sub> /R <sub>1</sub>		8.0	1	1.2	
Transition Frequency	$f_T$	$V_{CE}$ =10V, $I_E$ =-5mA, f=100MHz (Note)	·	250		MHz

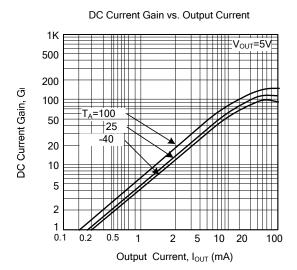
Note: Transition frequency of the device

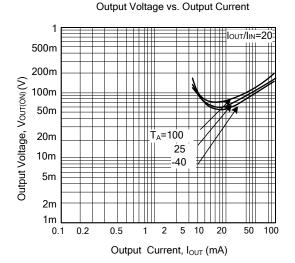
#### **■ TYPICAL CHARACTERISTIC**

Input Voltage vs. Output Current

(ON Characteristics) 100 V<sub>OUT</sub>=0.3\ 50 20 Input Voltage, VIN (ON) (V) 10 -25<u>0</u> 5 2 500m 200m 100m 0.2 0.5 2 20 50 5 0.1 1 10 100 Output Current, IOUT (A)







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